

HD74LS48

BCD-to-Seven-Segment Decoder / Driver (Internal Pull-up outputs)

REJ03D0411-0300 Rev.3.00 Jul.22.2005

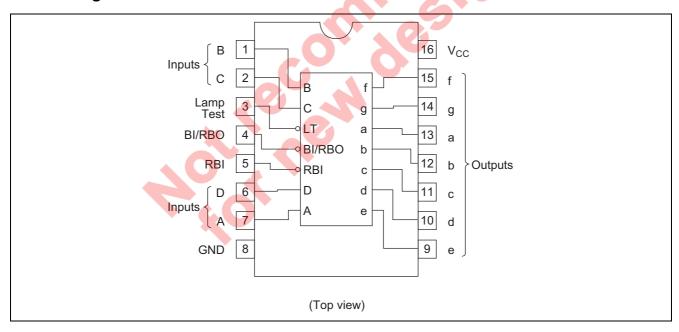
HD74LS48 features active high outputs for driving lamp buffers. This circuit has full ripple blanking input / output controls and a lamp test input. Display patterns for BCD input counts above 9 are unique symbols to authenticate input conditions. This circuit incorporates automatic leading and / or trailing-edge zero-blanking control (RBI and RBO). Lamp test (LT) of these types may be performed at any time when the BI / RBO node is at a high level. It contains an overriding blanking input (BI) which can be used to control the lamp intensity be pulsing or to inhibit the outputs. Inputs and outputs are entirely compatible for use with TTL or DTL logic outputs.

Features

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS48P	DILP-16 pin	PRDP0016AE-B (DP-16FV)	P	

Pin Arrangement



Function Table

Decimal or			Inpu	ıts			BI/			(Output	S			Note
Function	LT	RBI	D	С	В	Α	RBO	а	b	С	d	е	f	g	Note
0	Н	Н	L	L	L	L	Н	Η	Н	Н	Н	Н	Н	L	
1	Н	Χ	L	L	L	Н	Н	Ш	Н	Н	L	L	L	Ш	
2	Н	Χ	L	L	Η	L	Н	Ι	Н	L	Н	Н	L	Ι	
3	Н	Х	L	L	Н	Н	Н	Η	Н	Н	Н	L	L	Η	
4	Н	Х	L	Н	L	L	Н	L	Н	Н	L	L	Н	Н	
5	Н	Х	L	Н	L	Н	Н	Н	L	Н	Н	L	Н	Н	
6	Н	Х	L	Н	Н	L	Н	L	L	Н	Н	Н	Н	Н	
7	Н	Х	L	Н	Н	Н	Н	Н	Н	Н	L	L	L	L	1
8	Н	Х	Н	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	'
9	Н	Х	Н	L	L	Н	Н	Н	Н	Н	L	L	Н	Н	
10	Н	Х	Н	L	Н	L	Н	L	L	L	Н	Н	L	Н	
11	Н	Х	Н	L	Н	Н	Н	L	L	Н	Н	L	L	Н	
12	Н	Х	Н	Н	L	L	Н	L	Н	L	L	L	Н	Н	
13	Н	Χ	Н	Н	L	Н	Н	Н	L	L	Н	L	Н	Н	
14	Н	Х	Н	Н	Н	L	Н	L	L	Ц	Н	Н	Н	Н	
15	Н	Χ	Н	Н	Н	Н	Н	L	L	7	L	L	L	L	
BI	Х	Х	Х	Х	Х	Х	L	L	L	Ţ	4	L	L	L	2
RBI	Н	L	L	L	L	L	L	L	LS	Ľ	L	L	L	L	3
LT	L	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Η	4

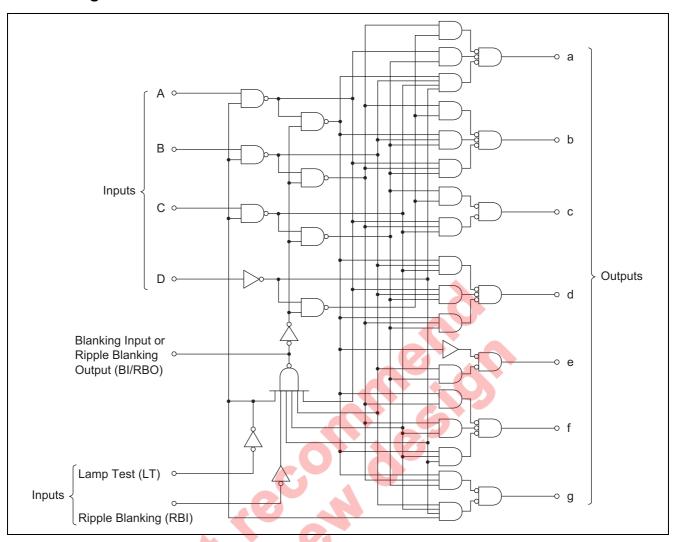
H; high level, L; low level, X, irrelevant

Notes: 1. The blanking input (BI) must be open or held at a high logic level when output functions 0 through 15 are desired.

- 2. When a low logic level is applied directly to the blanking input (BI), all segment outputs are low regardless of the level of any other input.
- 3. When ripple-blanking input (RBI) and inputs A, B, C, and D are at a low level with the lamp-test input high, all segment outputs go low and the ripple-blanking output (RBO) goes to a low level (response condition).
- 4. When a blanking input / ripple blanking output (BI / RBO) is open or held high and a low is applied to the lamp-test input, all segment outputs are high.



Block Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	V _{CC}	7	V
Input voltage	VI _N	7	V
Power dissipation	P _T	400	mW
Storage temperature	Tstg	-65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

Recommended Operating Conditions

Item	Symbol	Min	Тур	Max	Unit
Supply voltage	V _{CC}	4.75	5.00	5.25	V
Output current	I _{OH (a to g)}	_		-100	μΑ
Output current	I _{OH (BI/RBO)}	_		- 50	μΑ
Output current	I _{OL (a to g)}	_		6	mA
Output current	I _{OL (BI/RBO)}	_	_	3.2	mA
Operating temperature	Topr	-20	25	75	°C

Electrical Characteristics

 $(Ta = -20 \text{ to } +75 \text{ }^{\circ}\text{C})$

Item		Symbol	min.	typ.*	max.	Unit	C	ondition	
Input voltage		V_{IH}	2.0		_	V			
Input voltage		V_{IL}	_	_	0.8	V			
	a to g	V	2.4	_	_	V	$I_{OH} = -100 \mu A$	$V_{CC} = 4.75 \text{ V},$	
	BI / RBO	V _{OH}	2.4	_	_	V	$I_{OH} = -50 \mu A$	$V_{IH} = 2 \text{ V}, V_{IL} = 0.8 \text{ V}$	
Output voltage	o to a		_	_	0.4	V	$I_{OL} = 2 \text{ mA}$		
Output voltage	a to g	W	_	_	0.5	V	$I_{OL} = 6 \text{ mA}$	$V_{CC} = 4.75 \text{ V},$	
	BI / RBO	V_{OL}			0.4	V	$I_{OL} = 1.6 \text{ mA}$	$V_{IH} = 2 \text{ V}, V_{IL} = 0.8 \text{ V}$	
					0.5	V	$I_{OL} = 3.2 \text{ mA}$		
Output current**	a to g	lo	-1.3		_	mA	$V_{CC} = 4.75 \text{ V}, V_{O} = 0.85 \text{ V},$		
	except BI	I _{IH}			20	μΑ	$V_{CC} = 5.25 \text{ V}, V_{I} = 2.7 \text{ V}$		
	/ RBO	I _{IL}	_	_	-0.4	mA	$V_{CC} = 5.25 \text{ V}, V_I = 0.4 \text{ V}$		
Input current	BI / RBO				-1.2	mA	$V_{CC} = 5.25 \text{ V}, V_I = 0.4 \text{ V}$		
	except BI / RBO	I _I	1	1	0.1	mA	V _{CC} = 5.25 V, V	= 7 V	
Short-circuit output current	BI / RBO	los	-0.3	_	-2	mA	V _{CC} = 5.25 V		
Supply current***		Icc		25	38	mA	$V_{CC} = 5.25 \text{ V}$		
Input clamp volta	ge	V _{IK}	_	_	-1.5	V	$V_{CC} = 4.75 \text{ V}, I_{IN}$	ı = −18 mA	

Notes: * $V_{CC} = 5 \text{ V}$, $Ta = 25^{\circ}\text{C}$

Switching Characteristics

 $(V_{CC} = 5 \text{ V}, \text{Ta} = 25^{\circ}\text{C})$

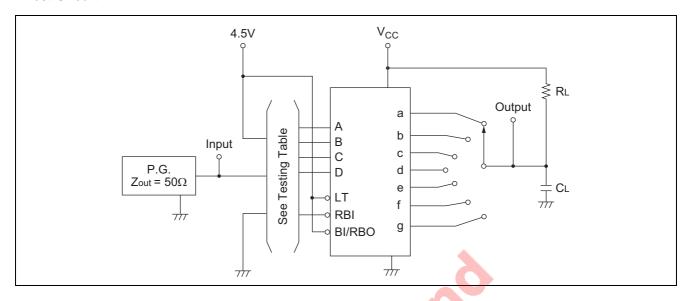
Item	Symbol	Input	min.	typ.	max.	Unit	Condition	
Turn-on time	t _{PHL}	A	1	<u> </u>	100	nc	$C_L = 15 \text{ pF}, R_L = 4 \text{ k}\Omega$	
Turn-on time	t _{PLH}	A		_	100	ns		
Turn-off time	t _{PHL}	RBI		_	100	ns	C - 15 pE D - 6kO	
Turr-on time	t _{PLH}	KDI	—	_	100	115	$C_L = 15 \text{ pF}, R_L = 6 \text{ k}\Omega$	

^{**} Input condition as for V_{OH}

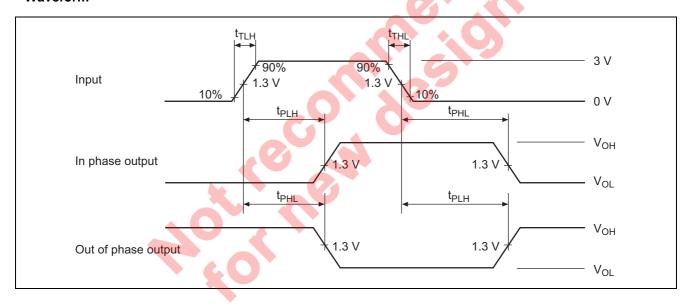
^{***} I_{CC} is measured with all outputs open and inputs at 4.5 V.

Testing Method

Test Circuit



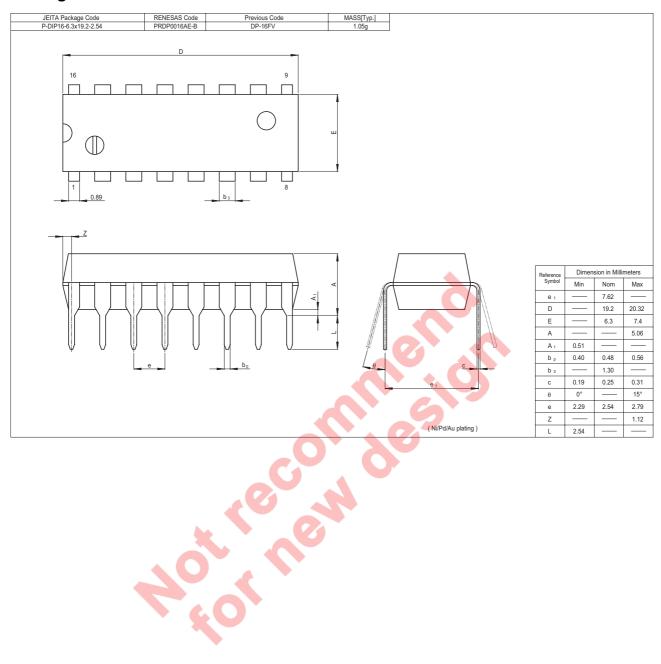
Waveform



Testing Table

Item			Inputs			Outputs						
пеш	RBI	D	С	В	Α	а	b	С	d	е	f	g
	4.5 V	GND	GND	GND	IN	OUT	_	_	OUT	OUT	OUT	_
t _{PLH}	4.5 V	GND	GND	4.5 V	IN	_	_	OUT	_	OUT	_	_
t _{PHL}	4.5 V	GND	4.5 V	4.5 V	IN	OUT	OUT	_	OUT	OUT	OUT	OUT
	IN	GND	GND	GND	GND	OUT	OUT	OUT	OUT	OUT	OUT	_

Package Dimensions



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